

Phase Transition and Doping induced Infrared Tunable Emission of AgInS₂ Luminescence Semiconductor

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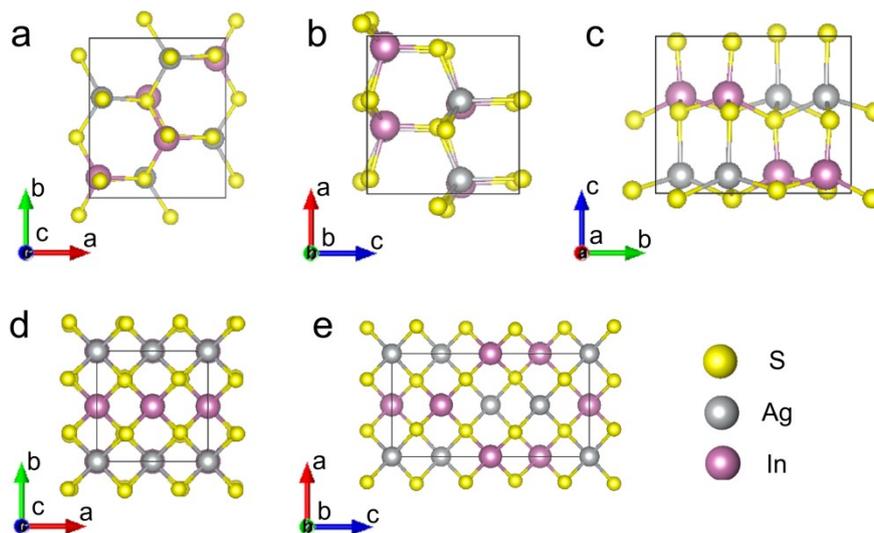


Figure S1. Schematic diagram of crystal structure for AgInS₂ orthorhombic (a-c), and tetragonal (d, e) along different directions view.

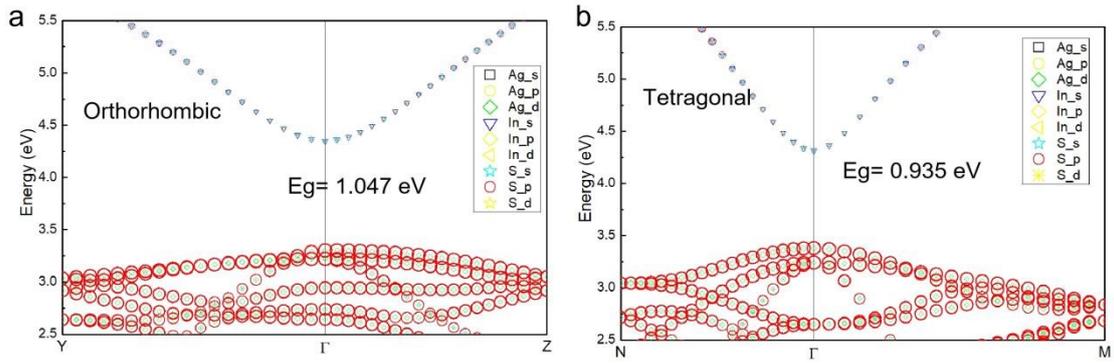


Figure S2. (a) XRD pattern of the AgIn_5S_8 , the insert is the crystal structure. (b) PL spectra of the AgIn_5S_8 crystal. (DFT Calculated Electronic Band Structures and Density of States for AgInS_2 Orthorhombic (a) and Tetragonal (b) Phases.)

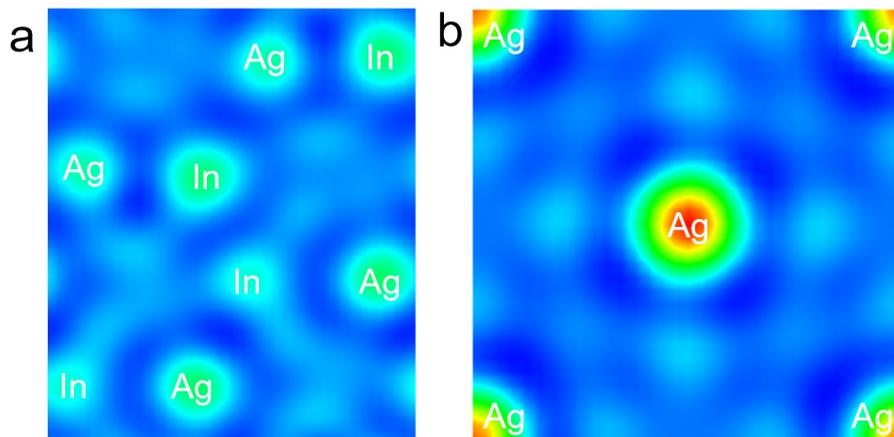


Figure S3. Charge density diagram of the AgInS_2 orthorhombic (a), and tetragonal (b).

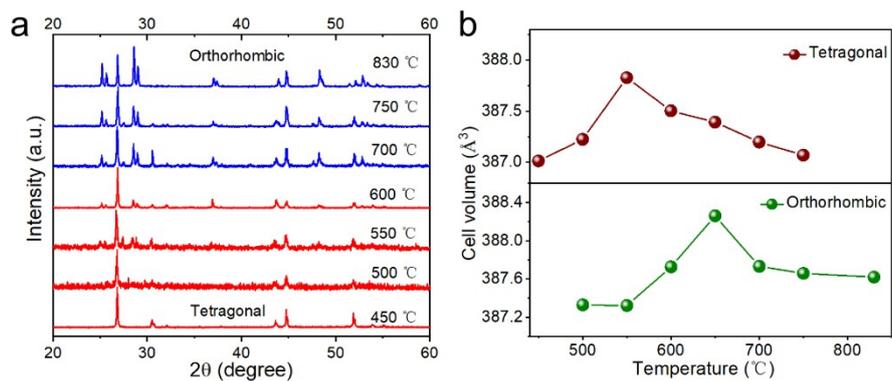


Figure S4. (a) XRD patterns of the AgInS₂ that produced from different temperature. (b) the cell volume revolution of the tetragonal and orthorhombic.

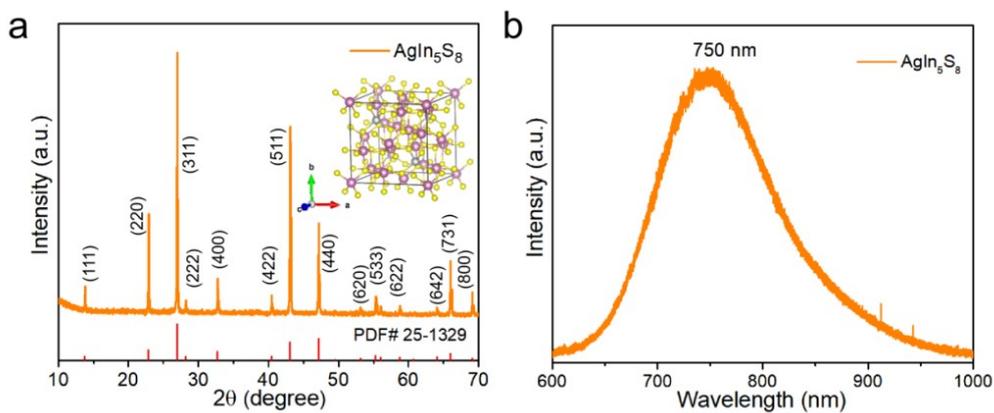


Figure S5. (a) XRD pattern of the AgIn₅S₈, the insert is the crystal structure. (b) PL spectra of the AgIn₅S₈ crystal.

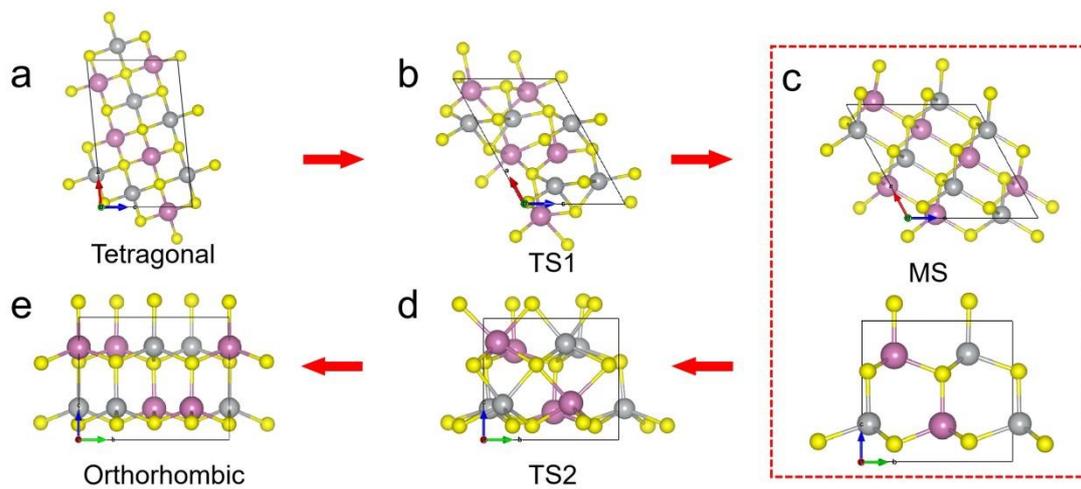


Figure S6. (a-e) Schematic diagram of the phase transition structure revolution from T→TS1→MS→TS2→O.

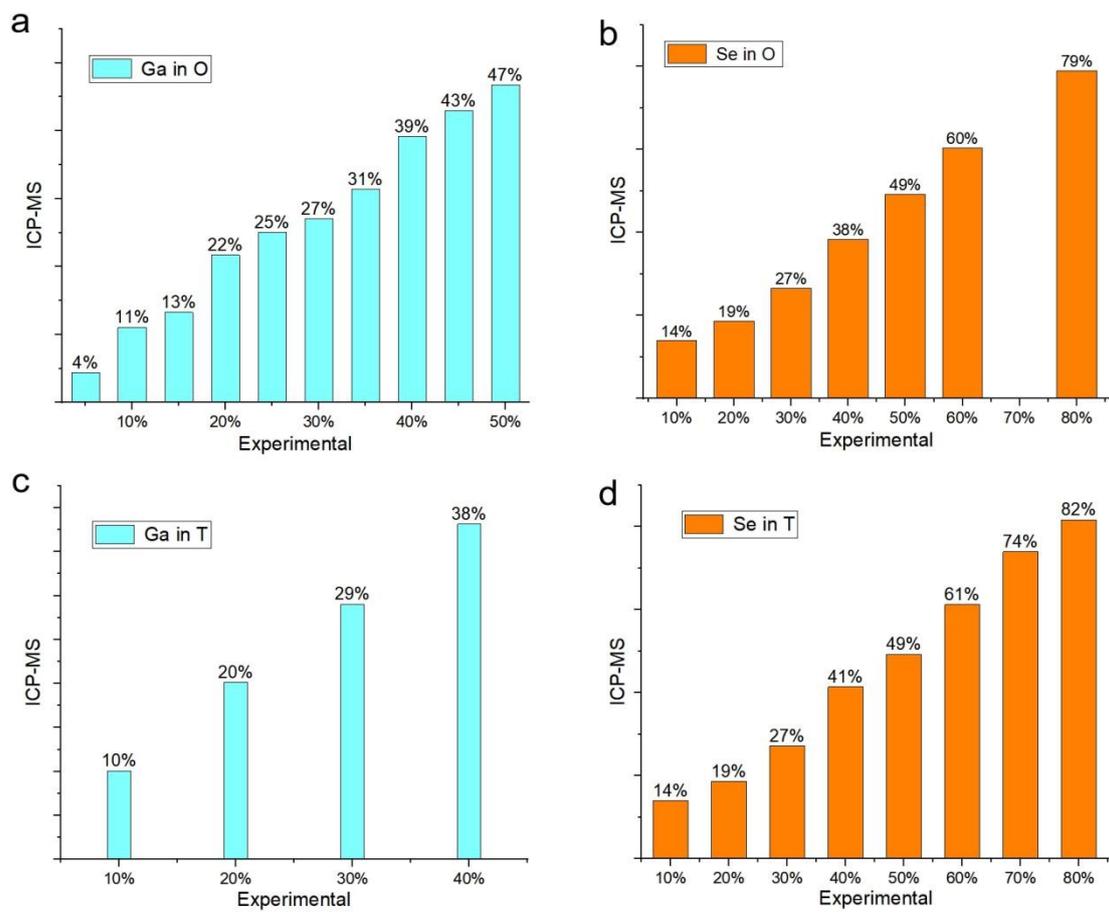


Figure S7. ICP-MS of the Se and Ga doping amount: (a) Se doping in O, (b) Ga doping in O, (c) Se doping in T, (d) Ga doping in T.

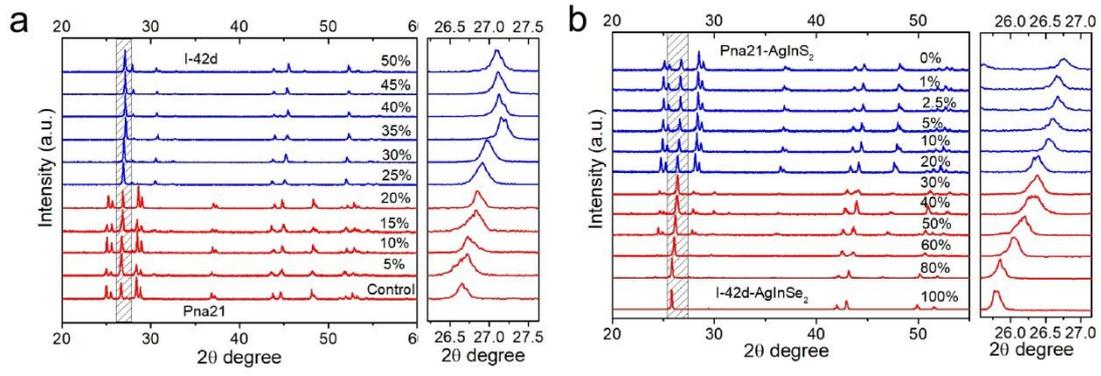


Figure S8. XRD pattern of the AgInS₂ doping with Ga (a) and Se (b), where, the orthorhombic is selected as host.

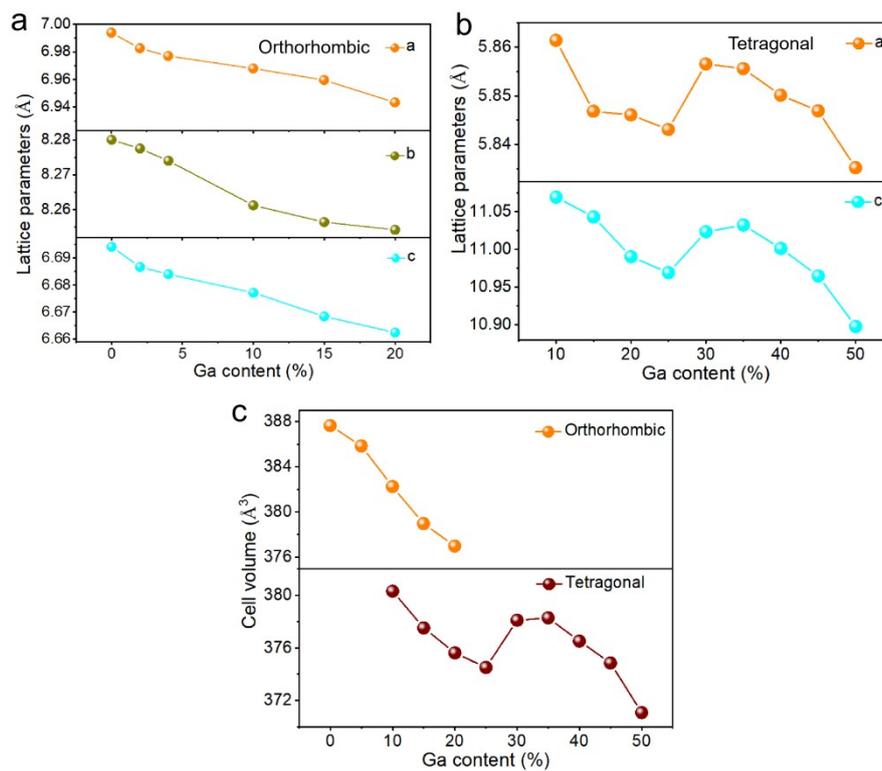


Figure S9. The lattice parameters (a, b) and cell volume (c) change as the Ga content increasing.

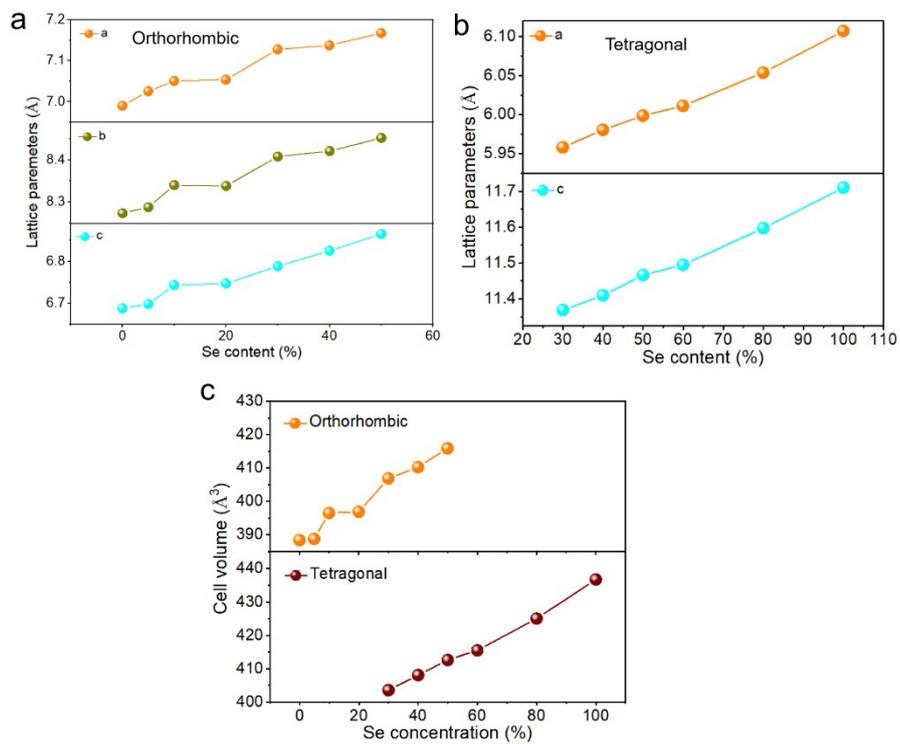


Figure S10. The lattice parameters (a, b) and cell volume (c) change as the Se content increasing.

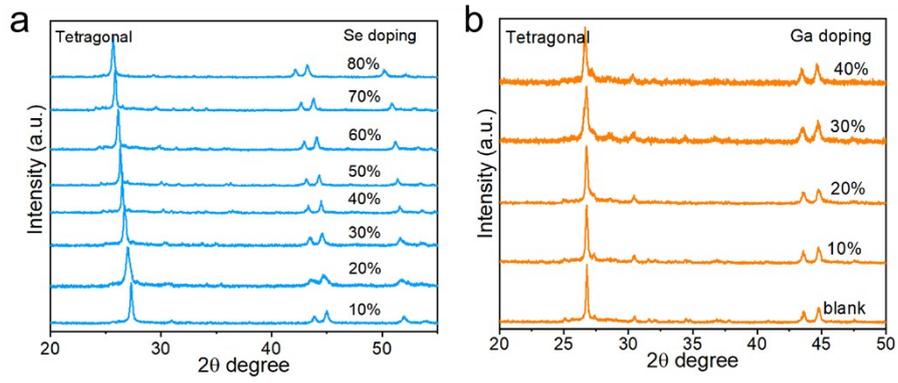


Figure S11. XRD pattern of the AgInS₂ doping with Ga (a) and Se (b), where, the host is tetragonal.

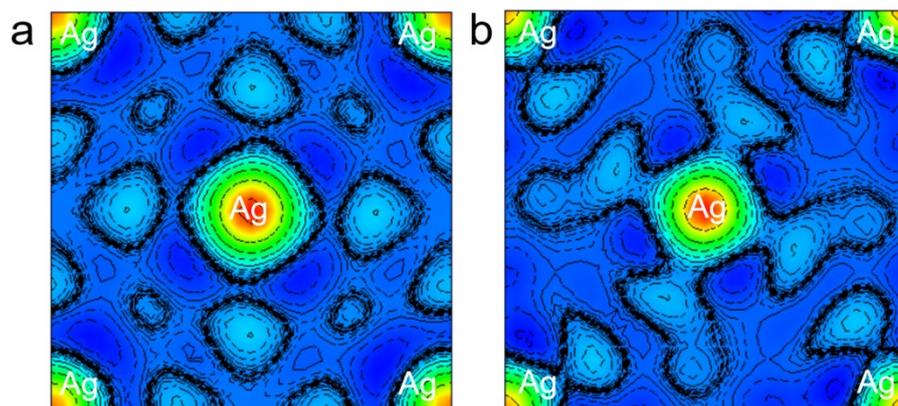


Figure S12. Charge density diagram of the AgInS₂ tetragonal (a) and Se 80% doping (b).

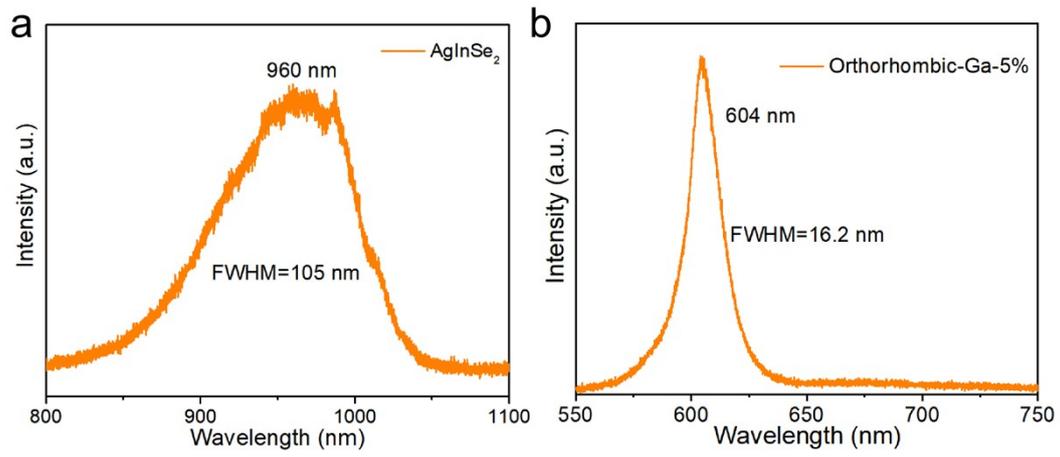


Figure S13. (a) PL pattern of the AgInSe₂ tetragonal. (b) PL pattern of the 5% Ga doped AgInS₂ orthorhombic.

Table S1. Crystallographic data for orthorhombic and tetragonal AgInS₂.

Empirical formula	AgInS ₂	AgInS ₂
Formula weight	286.69	286.69
Crystal system	Orthorhombic	Tetragonal
Space group	Pna21	I-42d
<i>a</i> (Å)	6.99006	5.8786
<i>b</i> (Å)	8.27351	5.8786
<i>c</i> (Å)	6.68837	11.2018
Volume (Å ³)	386.803	387.111
Density	4.926	4.921
χ^2	1.09	1.44
GOF	1.04	1.20
wR	12.156	14.7

Table S2. Structural data of AgInS₂ Orthorhombic phase

Crystal System	Orthorhombic	Space Group	Pna21	
Atom	Ag	In	S1	S2
Site Occupancy	1.00	1.00	1.00	1.00
x	0.40900	0.06700	0.09600	0.07800
y	0.12800	0.12900	0.62000	0.10800
z	0.11300	0.61800	0.01900	0.96500

Table S3. Structural data of AgInS₂ Tetragonal.

Crystal System	Tetragonal	Space Group	I-42d
Atom	Ag	In	S
Site Occupancy	1.00	1.00	1.00
x	0.00000	0.00000	0.26390
y	0.00000	0.00000	0.25000
z	0.00000	0.50000	0.12500

Table S4. Bond angle data for orthorhombic and tetragonal AgInS₂.

		[AgS4]	[InS4]
tetragonal	01	107.483	108.922
	02	113.526	110.575
orthorhombic	01	113.315	113.485
	02	110.169	110.282
	03	108.984	111.985
	04	103.706	103.628
	05	108.273	105.215
	06	112.275	111.892

Table S5. Calculated valance state of orthorhombic and tetragonal.

	tetragonal	orthorhombic
Ag	1.342	1.475
In	3.062	3.204
S1	-2.14	-2.316
S2	-	-2.362